National Semiconductor

# DS3487 Quad TRI-STATE<sup>®</sup> Line Driver

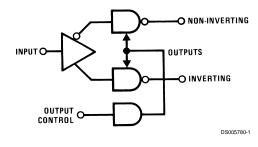
### **General Description**

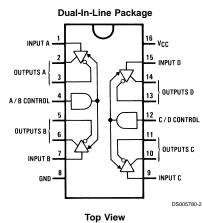
National's quad RS-422 driver features four independent drivers which comply with EIA Standards for the electrical characteristics of balanced voltage digital interface circuits. The outputs are TRI-STATE structures which are forced to a high impedance state when the appropriate output control pin reaches a logic zero condition. All input pins are PNP buffered to minimize input loading for either logic one or logic zero inputs.

#### Features

- Four independent drivers
- TRI-STATE <sup>®</sup> outputs
- Fast propagation times (typ 10 ns)
- TTL compatible
- 5V supply
- Output rise and fall times less than 15 ns
- Pin compatible with DS8924 and MC3487

# **Block and Connection Diagrams**





Order Number DS3487M or DS3487N See NS Package Number M16A or N16E

#### **Truth Table**

Input	Control Input	Non-Inverting Output	Inverting Output
Н	Н	Н	L
L	н	L	н
Х	L	Z	Z

L = Low logic state

H = High logic state

X = Irrelevant Z = TRI-STATE(high impedance) May 1998

### Absolute Maximum Ratings (Note 2)

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If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage	8V
Input Voltage	5.5V
Storage Temperature	–65°C to +150°C
Maximum Power Dissipation (Note 1) a	t 25°C
Molded DIP Package	1476 mW
SO Package	1051 mW
Lead Temperature	

#### (Soldering, 4 seconds)

**Operating Conditions** 

	Min	Max	Units
Supply Voltage, V <sub>CC</sub>			
DS3487	4.75	5.25	V
Temperature (T <sub>A</sub> )			
DS3487	0	+70	°C
Note 1: Derate DIP molded packag package 8.41 mW/°C above 25°C.	e 11.9 mW/°	C above 25°C.	Derate SO

260°C

## Electrical Characteristics (Notes 3, 4, 5, 6)

Symbol	Parameter	Co	nditions	Min	Тур	Max	Units
V <sub>IL</sub>	Input Low Voltage					0.8	V
V <sub>IH</sub>	Input High Voltage			2.0			V
I <sub>IL</sub>	Input Low Current	V <sub>IL</sub> = 0.5V				-200	μA
I <sub>IH</sub>	Input High Current		V <sub>IH</sub> = 2.7V			50	μA
			V <sub>IH</sub> = 5.5V			100	μA
V <sub>CL</sub>	Input Clamp Voltage	I <sub>CL</sub> = -18 mA	·			-1.5	V
V <sub>OL</sub>	Output Low Voltage	I <sub>OL</sub> = 48 mA				0.5	V
V <sub>OH</sub>	Output High Voltage	I <sub>он</sub> = –20 mA		2.5			V
los	Output Short-Circuit Current			-40		-140	mA
l <sub>oz</sub>	Output Leakage Current		V <sub>O</sub> = 0.5V			-100	μA
	(TRI-STATE)		V <sub>O</sub> = 5.5V			100	μA
IOFF	Output Leakage Current Power OFF	$V_{\rm CC} = 0V$	V <sub>O</sub> = 6V			100	μA
			$V_{\rm O} = -0.25V$			-100	μA
V <sub>os</sub> - V osl	Difference in Output Offset Voltage					0.4	V
V <sub>T</sub>	Differential Output Voltage			2.0			V
$ V_T  - \overline{V}_T $	Difference in Differential Output Voltage					0.4	V
I <sub>cc</sub>	Power Supply Current		Active		50	80	mA
			TRI-STATE®		35	60	mA

# **Switching Characteristics**

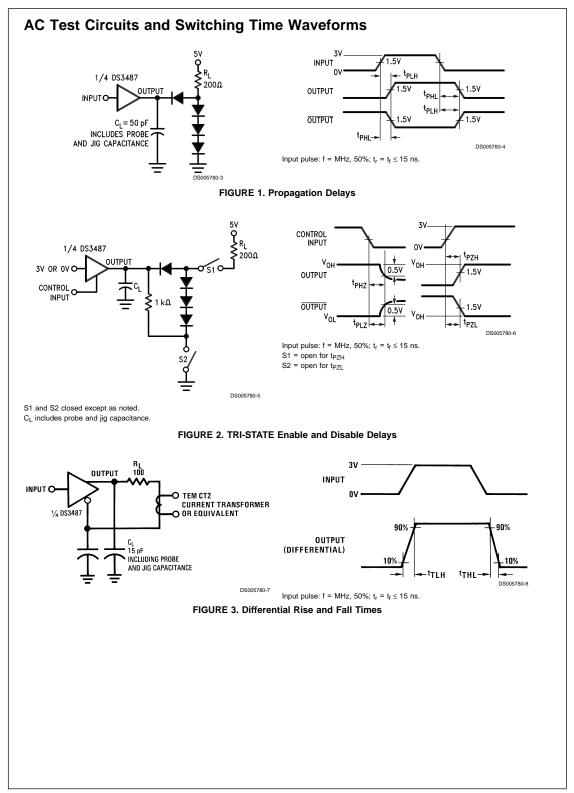
Symbol	Parameter	Conditions	Min	Тур	Max	Units
t <sub>PHL</sub>	Input to Output			10	15	ns
t <sub>PLH</sub>	Input to Output			10	15	ns
t <sub>THL</sub>	Differential Fall Time			10	15	ns
t <sub>TLH</sub>	Differential Rise Time			10	15	ns
t <sub>PHZ</sub>	Enable to Output	$R_{L} = 200\Omega, C_{L} = 50 \text{ pF}$		17	25	ns
t <sub>PLZ</sub>	Enable to Output	$R_{L} = 200\Omega, C_{L} = 50 \text{ pF}$		15	25	ns
t <sub>PZH</sub>	Enable to Output	$R_L = \infty$ , $C_L = 50 \text{ pF}$ , S1 Open		11	25	ns
t <sub>PZL</sub>	Enable to Output	$R_{L} = 200\Omega, C_{L} = 50 \text{ pF}, S2 \text{ Open}$		15	25	ns

Note 2: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

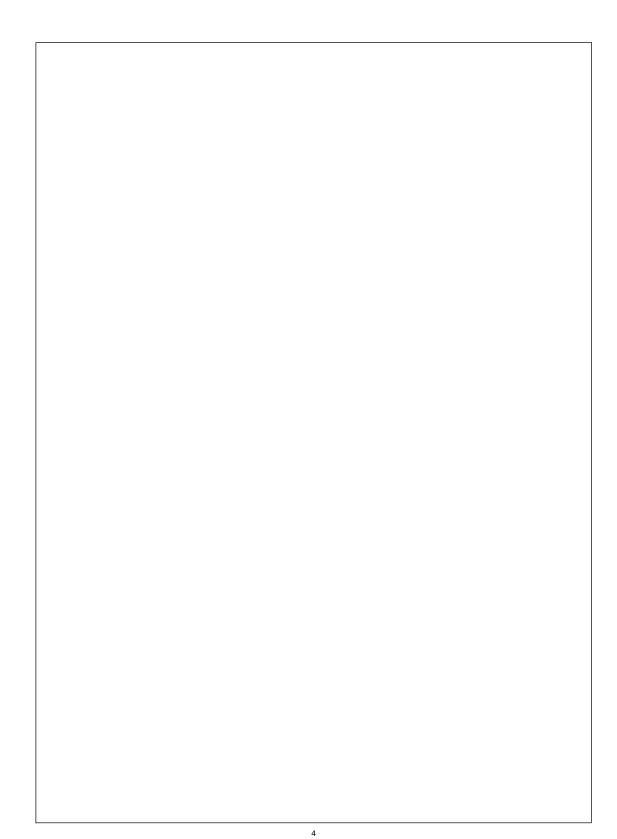
Note 3: Unless otherwise specified min/max limits apply across the 0°C to +70°C range for the DS3487. All typicals are given for V<sub>CC</sub> = 5V and T<sub>A</sub> = 25°C.

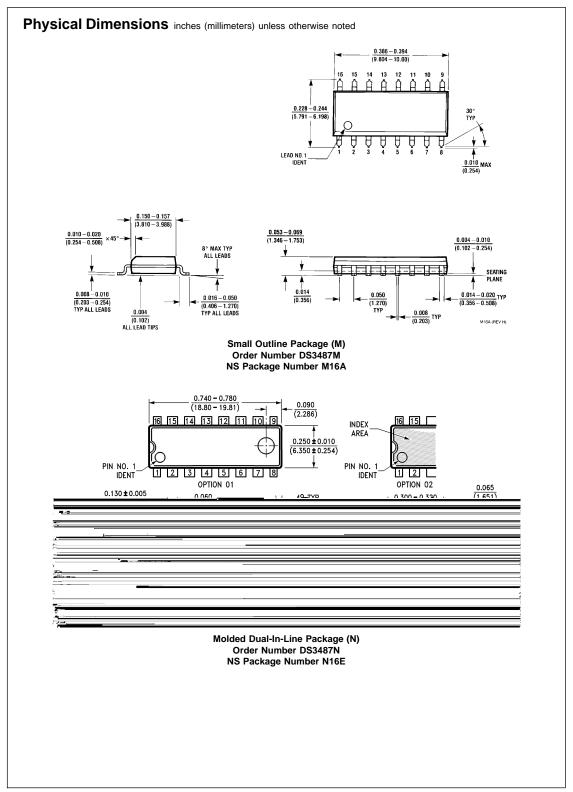
Note 4: All currents into device pins are positive, all currents out of device pins as negative. All voltages are referenced to ground unless otherwise specified. Note 5: Only one output at a time should be shorted.

Note 6: Symbols and definitions correspond to EIA RS-422, where applicable.



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